ULSI Technology

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To Our Colleagues and Students— Past, Present, and Future On the Centennial of Our University-The National Chiao Tung University

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CONTENTS

	List	of Contributors	xiii
	Prefa	XV	
	Introduction		xvii
1	Clea	anroom Technology	1
	H. P. Tseng and R. Jansen		
	1.1	Introduction	1
	1.2	Cleanroom Classification	4
	1.3	Cleanroom Design Concept	8
	1.4	Cleanroom Installation	24
	1.5	Cleanroom Operations	32
	1.6	Automation	34
	1.7	Related Facility Systems	38
	1.8	Summary and Future Trends	54
		References	55
		Problems	58
2	Wafer-Cleaning Technology		60
	<i>C. Y</i>	Chang and T. S. Chao	
	2.1	Introduction	60
	2.2	Basic Concepts of Wafer Cleaning	60
	2.3	Wet-Cleaning Technology	92
	2.4	Dry-Cleaning Technology	93
	2.5	Summary and Future Trends	100
		References	101
		Problems	104
3	Epitaxy		105
	P. Wang		
	3.1	Introduction	105
	3.2	Fundamental Aspects of Epitaxy	107
	3.3	Conventional Si Epitaxy	115
	3.4	Low-Temperature Epitaxy of Si	125
	3.5	Selective Epitaxial Growth of Si	131

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